



## DESCRIPTION

The A7131A is a monolithic step-down DC/DC converter capable of delivering up to 3A of output current without requiring an external transistor, saving board space. The device features a low EMI signature and can operate at 100% duty cycle for low-dropout operation.

The internal soft-start function limits inrush current, helping to extend battery life in portable systems. Protection features include cycle-by-cycle peak current limiting, short-circuit protection, thermal shutdown, and UVLO.

The device is available in SOT-26 package.

## ORDERING INFORMATION

| Package Type                   | Part Number                               |            |
|--------------------------------|-------------------------------------------|------------|
| SOT-26<br>SPQ:3,000pcs/Reel    | E6                                        | A7131AE6R  |
|                                |                                           | A7131AE6VR |
| Note                           | V: Halogen free Package<br>R: Tape & Reel |            |
| AiT provides all RoHS products |                                           |            |

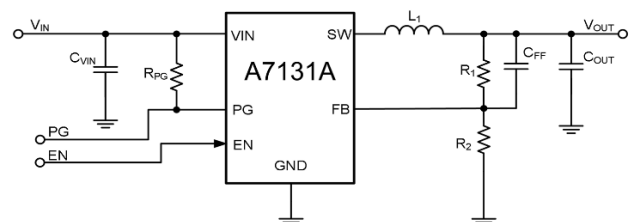
## FEATURES

- Wide input voltage Range: 2.5V~5.5V
- Adjustable Output Voltage from 0.6V to  $V_{IN}$
- Low  $R_{DS(ON)}$  Switches 80m $\Omega$  / 55m $\Omega$
- Output Discharge Resistance: 20 $\Omega$
- 1MHz Typical Switching Frequency
- Duty Cycle up to 100%
- Short Circuit Protection
- Over Current Protection
- Internal Soft Startup
- Thermal Shutdown Protection

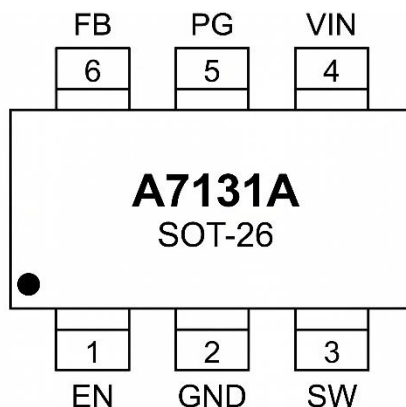
## APPLICATION

- LCD Monitor and LCD TV
- Battery-powered Equipment
- Entertainment Devices
- Digital Home Appliances: Digital TVs

## TYPICAL APPLICATION



L1: PIA4030-1R0N or PIA5040-1R5N

**PIN DESCRIPTION**

SOT-26, E6

Top View

| PIN# | Symbol | Function                                                                                                                                                              |
|------|--------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 1    | EN     | Device enable logic input. Logic high enables the device, logic low disables the device and turns it into shutdown. Do not leave floating.                            |
| 2    | GND    | Ground pin.                                                                                                                                                           |
| 3    | SW     | Switch pin connected to the internal FET switches and inductor terminal. Connect the inductor of the output filter to this pin.                                       |
| 4    | VIN    | Power supply voltage input.                                                                                                                                           |
| 5    | PG     | Power Good Indicator Pin. The open-drain output is high-impedance when the output voltage is within $\pm 10\%$ of the regulation voltage and is pulled low otherwise. |
| 6    | FB     | Feedback pin for the internal control loop. Connect this pin to an external feedback divider.                                                                         |



## ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range, unless otherwise noted

|                                                                   |                               |
|-------------------------------------------------------------------|-------------------------------|
| V <sub>IN</sub> , and EN Voltage                                  | -0.3V ~ 6V                    |
| SW, Voltage                                                       | -0.3V ~ V <sub>IN</sub> +0.3V |
| FB, Voltage                                                       | - 0.3V ~ 6V                   |
| T <sub>J</sub> , Operating Junction Temperature                   | -40°C ~ +150°C                |
| T <sub>STG</sub> , Storage Temperature                            | -65°C ~ +150°C                |
| R <sub>θJA</sub> , Junction-to-Ambient Thermal Resistance         | 240°C/W                       |
| R <sub>θJC</sub> (top), Junction-to-Case (Top) Thermal Resistance | 140°C/W                       |

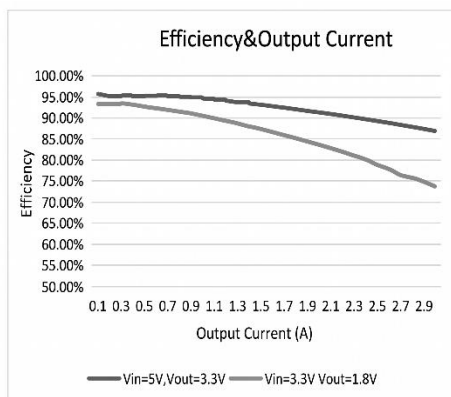
Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## RECOMMENDED OPERATING CONFITIONS

T<sub>C</sub>= 25°C, unless otherwise specified.

| Parameter                      | Symbol          | Conditions | Min | Typ | Max | Unit |
|--------------------------------|-----------------|------------|-----|-----|-----|------|
| Operating Junction Temperature | -               | -          | -40 | -   | 125 | °C   |
| Operating temperature range    | -               | -          | -40 | -   | 85  | °C   |
| Input Voltage                  | V <sub>IN</sub> | -          | 2.5 | -   | 5.5 | V    |
| Output Current                 | -               | -          | 0   | -   | 3.0 | A    |

## EFFICIENCY

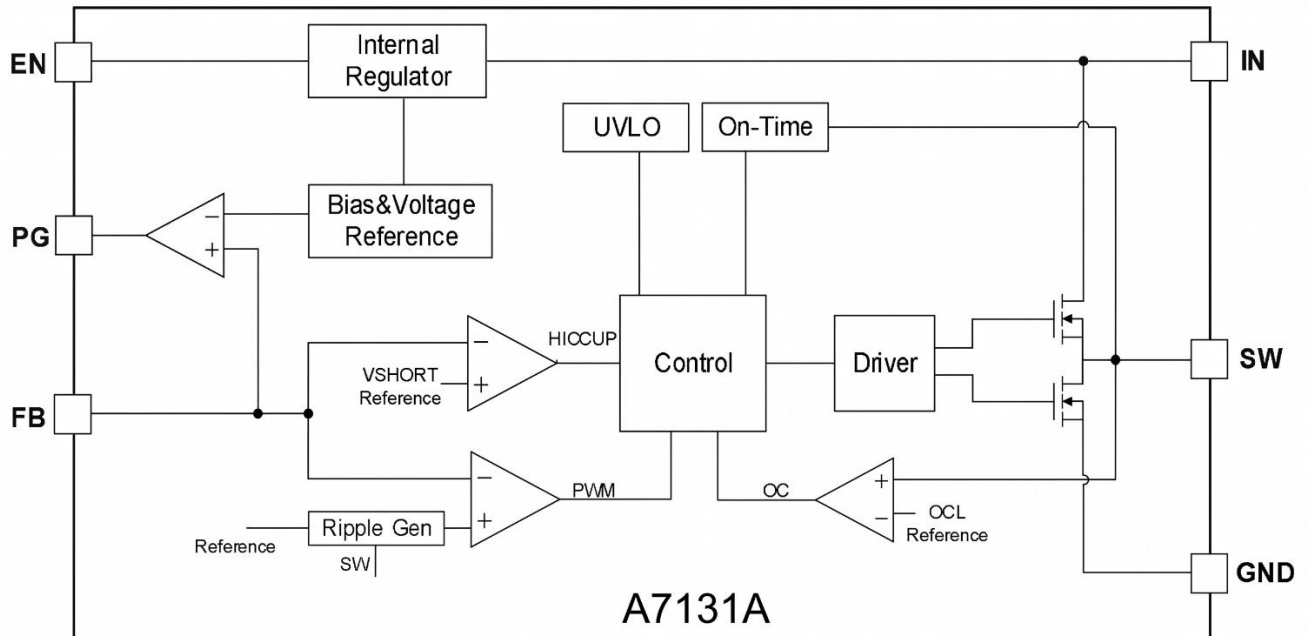


**ELECTRICAL CHARACTERISTICS**T<sub>A</sub> = 25°C, V<sub>IN</sub> = 5V, unless otherwise specified.

| Parameter                                        | Symbol                    | Test Condition                  | Min. | Typ. | Max. | Units |
|--------------------------------------------------|---------------------------|---------------------------------|------|------|------|-------|
| Input voltage range                              | V <sub>IN</sub>           | -                               | 2.5  | -    | 5.5  | V     |
| Non switching quiescent current                  | I <sub>Q</sub>            | OUT=1.8V, I <sub>load</sub> =0A | -    | 40   | 75   | μA    |
| Shutdown current                                 | I <sub>OFF</sub>          | EN = GND                        | -    | -    | 1    | μA    |
| Regulated Feedback Voltage                       | V <sub>FB</sub>           | -                               | 588  | 600  | 612  | mV    |
| V <sub>IN</sub> under voltage lockout            | V <sub>IN(UVLO)</sub>     | -                               | -    | 2.2  | -    | V     |
| V <sub>IN</sub> under voltage lockout Hysteresis |                           | -                               | -    | 300  | -    | mV    |
| ENABLE (EN PIN)                                  |                           |                                 |      |      |      |       |
| Enable threshold                                 | V <sub>(EN_RISING)</sub>  | Rising                          | 1.2  | -    | -    | V     |
|                                                  | V <sub>(EN_FALLING)</sub> | Falling                         | -    | -    | 0.4  | V     |
| Threshold Hysteresis                             | V <sub>(EN_HYS)</sub>     | -                               | -    | 270  | -    | mV    |
| POWER STAGE                                      |                           |                                 |      |      |      |       |
| High-side FET on resistance                      | R <sub>(HSD)</sub>        | I <sub>sw</sub> =100mA          | -    | 80   | -    | mΩ    |
| Low-side FET on resistance                       | R <sub>(LSD)</sub>        | I <sub>sw</sub> =-100mA         | -    | 55   | -    | mΩ    |
| Output Discharge Resistance                      | -                         | -                               | -    | 20   | -    | Ω     |
| CURRENT LIMIT                                    |                           |                                 |      |      |      |       |
| High-side FET current limit                      | I <sub>(LIM_HS)</sub>     | FB=90%                          | -    | 4    | -    | A     |
| Low side FET current limit                       | I <sub>(LIM_LS)</sub>     | FB=90%                          | -    | 3    | -    | A     |
| OSCILLATOR                                       |                           |                                 |      |      |      |       |
| Centre switching frequency                       | F <sub>SW</sub>           | OUT=1.8V, I <sub>load</sub> =1A | -    | 1.0  | -    | MHz   |
| OVER TEMPERATURE PROTECTION                      |                           |                                 |      |      |      |       |
| Rising temperature                               | Thermal                   | -                               | -    | 160  | -    | °C    |
| Hysteresis                                       | Shutdown                  | -                               | -    | 30   | -    | °C    |
| Soft start                                       | -                         | -                               | 0.5  | 1    | 1.5  | ms    |



## BLOCK DIAGRAM





## DETAILED INFORMATION

### Overview

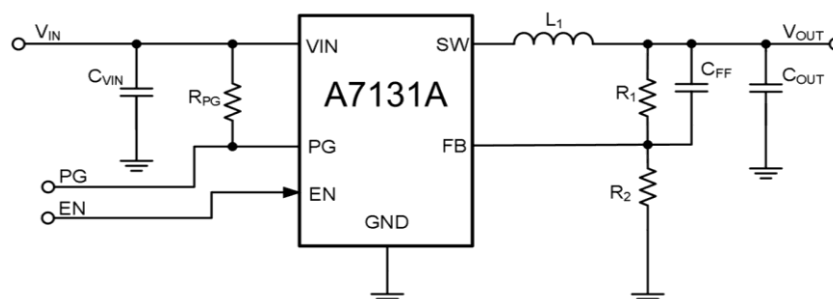
The A7131A is a high-output-current, monolithic step-down DC/DC converter designed to deliver up to 3A of output current from an input voltage ranging from 2.5V to 5.5V. The device operates at a fixed 1MHz switching frequency and utilizes a slope-compensated current-mode control architecture.

The external shutdown function can be controlled by a logic-level signal to place the device into standby mode. Internal compensation simplifies the design and provides good line and load regulation without requiring external compensation components. For protection, the A7131A incorporates thermal shutdown to prevent damage caused by excessive operating temperature and cycle-by-cycle current limiting to protect the internal power switch from overcurrent conditions. When the current-limit condition occurs and  $V_{FB}$  falls below 0.6V, the switching frequency is reduced to provide additional protection under severe load conditions.

### Application information

The A7131A is a high-performance, monolithic step-down converter with a wide 2.5V to 5.5V input voltage range and up to 3A output current. The device operates at a fixed 1MHz switching frequency and requires only a few external power components, including  $C_{IN}$ ,  $C_{OUT}$ , and  $L_1$ . The output voltage can be programmed using an external feedback network to any voltage from 0.6V up to the input voltage.

$$V_{OUT} = 0.6 \times \frac{R_1 + R_2}{R_2}$$



**Table 1. Recommended Component Values**

| V <sub>OUT</sub> (V) | L1 (μH) | C <sub>IN</sub> (μF) | C <sub>OUT</sub> (μF) | C <sub>FF</sub> Opt.(pF) | R <sub>PG</sub> (kΩ) | R1 (kΩ) | R2 (kΩ) |
|----------------------|---------|----------------------|-----------------------|--------------------------|----------------------|---------|---------|
| 1                    | 1       | 10                   | 22                    | 10~100                   | 100                  | 6.67    | 10      |
| 1.5                  | 1       | 10                   | 22                    | 10~100                   | 100                  | 15      | 10      |
| 1.8                  | 1       | 10                   | 22                    | 10~100                   | 100                  | 20      | 10      |
| 3.3                  | 1       | 10                   | 22                    | 10~100                   | 100                  | 45      | 10      |

**Table 2 . Reference inductor model**

| Input Voltage (V) | Output Voltage | Output Current | Inductance | Inductor model       |
|-------------------|----------------|----------------|------------|----------------------|
| 5                 | 1              | 3              | 0.899      | PIA4030-1R0N (1μH)   |
| 5                 | 1.5            | 3              | 1.167      | PIA5040-1R5N(1.5μH)  |
| 5                 | 1.8            | 3              | 1.280      | PIA5040-1R5N (1.5μH) |
| 5                 | 3.3            | 3              | 1.247      | PIA5040-1R5N (1.5μH) |

**Note:** The inductor values provided are for reference only. The required inductance should be recalculated based on the actual application conditions, including input voltage, output voltage, load current, switching frequency, and other relevant parameters.

### Power Supply Recommendations

The devices are designed to operate from an input voltage supply range between 2.5V and 5.5V. This input supply must be well regulated. If the input supply is located more than a few inches from the device or converter, additional bulk capacitance may be required in addition to the ceramic bypass capacitors. An electrolytic capacitor with a value of 47 μF is a typical choice.

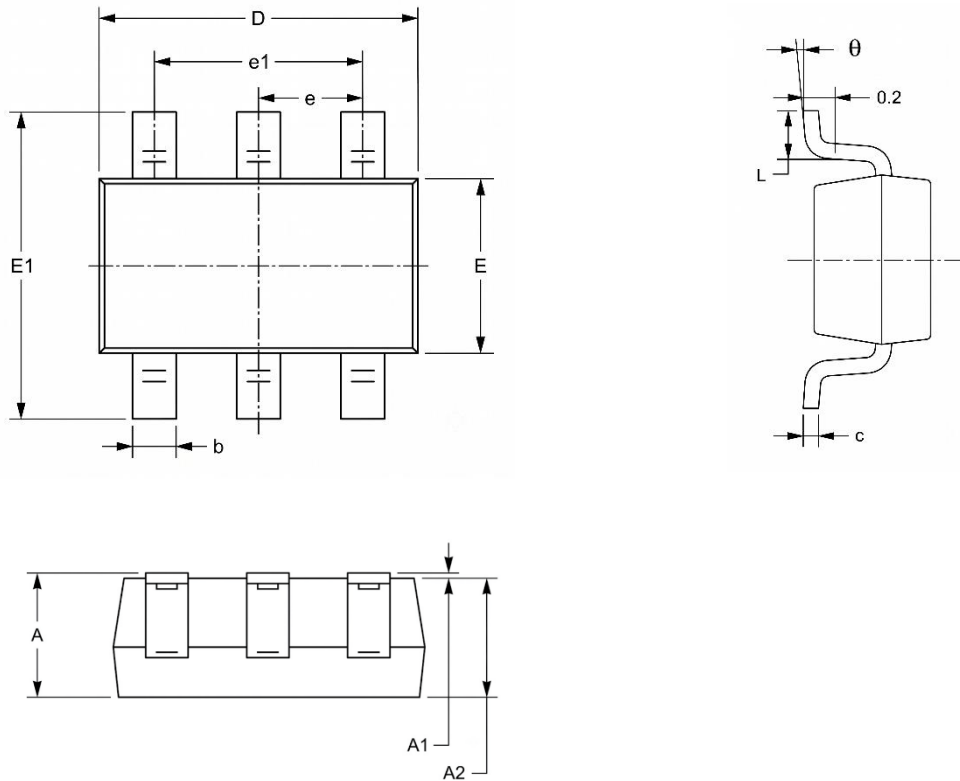
### Layout Guidelines

- VIN and GND traces should be as wide as possible to reduce trace impedance. The wide areas are also of advantage from the viewpoint of heat dissipation.
- The input capacitor and output capacitor should be placed as close to the device as possible to minimize trace impedance.
- Provide sufficient vias for the input capacitor and output capacitor.
- Keep the SW trace as physically short and wide as practical to minimize radiated emissions.
- Do not allow switching current to flow under the device.
- A separate VOUT path should be connected to the upper feedback resistor.
- Make a Kelvin connection to the GND pin for the feedback path.
- Voltage feedback loop should be placed away from the high-voltage switching trace, and preferably has ground shield.
- The trace of the VFB node should be as small as possible to avoid noise coupling.
- The GND trace between the output capacitor and the GND pin should be as wide as possible to minimize its trace impedance.



## PACKAGE INFORMATION

Dimension in SOT-26 (Unit: mm):



| Symbol | MILLIMETERS |       |
|--------|-------------|-------|
|        | Min.        | Max.  |
| A      | 1.050       | 1.250 |
| A1     | 0.000       | 0.100 |
| A2     | 1.050       | 1.150 |
| b      | 0.300       | 0.500 |
| c      | 0.100       | 0.200 |
| D      | 2.820       | 3.020 |
| E      | 1.500       | 1.700 |
| E1     | 2.650       | 2.950 |
| e      | 0.950 BSC   |       |
| e1     | 1.900 BSC   |       |
| L      | 0.300       | 0.600 |
| θ      | 0°          | 8°    |

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